
	<p><b>IPD60R950C6</b></p>
	<p><b>Hersteller-Teilenummer:</b> IPD60R950C6</p> <p><b>Hersteller / Marke:</b> International Rectifier (Infineon Technologies)</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 600V 4.4A TO252</p> <p><b>Datenblätter:</b>  <a href="#">IPD60R950C6.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 32805 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	IPD60R950C6
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	MOSFET N-CH 600V 4.4A TO252
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	32805 pcs Stock
Serie	CoolMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	PG-TO252-3
Verlustleistung (max)	37W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4.4A (Tc)
Rds On (Max) @ Id, Vgs	950 mOhm @ 1.5A, 10V
VGS (th) (Max) @ Id	3.5V @ 130µA
Gate Charge (Qg) (Max) @ Vgs	13nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	280pF @ 100V
Verpackung	Tape & Reel (TR)

IPD60R950C6 ist neu im Original, Suche IPD60R950C6 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IPD60R950C6 International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IPD60R950C6: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>IPD60R800CEAUMA1</b> International Rectifier (Infineon Technologies) CONSUMER</p>	 <p><b>IPD60S400CE</b> International Rectifier (Infineon Technologies) IPD60S400CE INFINEON</p>	 <p><b>IPD640N06LG</b> INFINEO IPD640N06LG INFINEO</p>	 <p><b>IPD60R950C6ATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 600V 4.4A TO252</p>
 <p><b>IPD640N06LGBTMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 60V 18A TO-252</p>	 <p><b>IPD60R750E6ATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 600V 5.7A TO252</p>	 <p><b>IPD60R800CE</b> INF IPD60R800CE INF</p>	 <p><b>IPD640N06L G</b> INFINEO IPD640N06L G INFINEO</p>

heiße Teile

Mehr

 IPD530N15N3	 IPD530N15N3G	 IPD530N15NG	 IPD600N25N3G	 IPD60N10S4L-12
 IPD60R1K0CE	 IPD60R1K4C6	 IPD60R1K5CE	 IPD60R2K0C6	 IPD60R360P
 IPD60R380C6	 IPD60R380E6	 IPD60R380P6	 IPD60R385CP	 IPD60R3K3C6
 IPD60R400CE	 IPD60R450E6	 IPD60R520C6	 IPD60R520CP	 IPD60R600C6
 IPD60R600CP	 IPD60R600E6	 IPD60R600P6	 IPD60R750E6	 IPD60R800CE
 IPD640N06LG	 IPD64CN10NG	 IPD65R1K4C6	 IPD65R250C6	 IPD65R250E6
 IPD65R380C6	 IPD65R380E6	 IPD65R420CFD	 IPD65R420CFDA	 IPD65R600C6
 IPD65R600E6	 IPD65R660CFD	 IPD65R950C6	 IPD65R950CFD	 IPD70N03S4L-04
 IPD70N03S4L04XT	 IPD70N04S3-07	 IPD70N10S3-12	 IPD70N10S3L-12	 IPD70P04P4-09
 IPD70P04P4L-08	 IPD75N04S4-06	 IPD78CN10NG	 IPD800N06NG	 IPD80N04S3-06

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